

W005M THRU W10M

SINGLE-PHASE SILICON BRIDGE Reverse Voltage - 50 to 1000 Volts Forward Current - 1.5 Amperes

Features



Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

	Symbols	W005M	W01M	W02M	W04M	W06M	W80W	W10M	Units
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified current $\rm T_A=25^{\circ}C$	I _(AV)	1.5							Amps
Peak forward surge current, 8.3mS single half sine-wave superimposed on rated load	I _{FSM}	50.0							Amps
1²t Rating for fusing (t<8.35ms)	l²t	5.0							A²t
Maximum forward voltage drop per element at 1.0A peak	V _F	1.0							Volt
Maximum DC reverse current at rated $T_A=25^{\circ}C$ DC blocking voltage per element $T_A=100^{\circ}C$	I _R	10.0 1.0							μ A mA
Operating temperature range	T _J	-55 to +125							$^{\circ}\!\mathbb{C}$
Storage temperature range	T _{stg}	-55 to +150							$^{\circ}$ C

RATINGS AND CHARACTERISTIC CURVES





